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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Jochen Kraft et al.
Serial No. : N/A
Filed : N/A
Title : TRANSISTOR

Art Unit : Unknown
Examiner : Unknown

Commissioner for Patents
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Alexandria, VA 22313-1450


INFORMATION DISCLOSURE STATEMENT

Applicant submits the references listed on the attached form PTO-1449.

This statement is being filed with the application. Accordingly, only copies of foreign patent documents and non-patent literature are enclosed. Please apply any charges or credits to Deposit Account No. 06-1050.

Respectfully submitted,

Date: June 23, 2004


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Substitute Form PTO-1449 (Modified)	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 14603-007US1	Application No. 10/500079
Information Disclosure Statement by Applicant (Use several sheets if necessary) (37 CFR §1.98(b))		Applicant Jochen Kraft et al.	
		Filing Date	Group Art Unit

U.S. Patent Documents							
Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
	AA	5,589,409	12/31/96	Constantin Bulucca et al			
	AB	5,962,880	10/05/99	Katsuya Oda et al			
	AC	5,693,979	12/02/97	Fumihiko Sato			
	AD	6,563,147	05/13/03	Tatsuhiko Ikeda			
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						

Foreign Patent Documents or Published Foreign Patent Applications								
Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AL	WO01/91162	11/29/01	WIPO				
	AM	04099328	03/31/92	Abstracts of Japan				
	AN	0 701 287	03/13/96	EPO				
	AO	1 263 052	12/04/02	EPO				
	AP	100 60 584	07/19/01	Germany			Abstract	

Other Documents (include Author, Title, Date, and Place of Publication)		
Examiner Initial	Desig. ID	Document
	AQ	Böck, J. et al. "SiGe Bipolar Technology for Mixed Digital and Analogue RF Applications" Infineon Technologies, 2000 IEEE; 0-7803-6441-4
	AR	Gruhle, A. et al. "The Reduction of Base Dopant Outdiffusion in SiGe Heterojunction Bipolar Transistors by Carbon Doping" Applied Physics Letter 1999, Vol 75, No. 9 pp. 1311-1313 XP000868226
	AS	Ryum, B.R. et al "MBE-grown SiGe base HBT with Polysilicon-emitter and TiSi2 Base Ohmic Layer" Solid-State Electronics 1996, Vol 39, No. 11, pp 1643-1648, XP000635613
	AT	Osten, H.L. et al "The Effect of Carbon Incorporation on SiGe Heterobipolar Transistor Performance and Process Margin" Electron Devices Meeting 1997, pp 803-806 XP10265625

Examiner Signature	Date Considered
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	

Substitute Form PTO-1449 (Modified)	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 14603-007US1	Application No. 107500079
Information Disclosure Statement by Applicant (Use several sheets if necessary) (37 CFR §1.98(b))		Applicant Jochen Kraft et al.	
		Filing Date	Group Art Unit

Other Documents (include Author, Title, Date, and Place of Publication)		
Examiner Initial	Desig. ID	Document
	AU	Liu J.P. et al "Substitutional Carbon Incorporation During Si _{1-x-y} GexCy Growth on Si(100) by Molecular-beam Epitaxy: Dependence on Germanium and Carbon" Applied Physics Letters; 2000, Vol. 76, No. 24 pp. 3546-3548

Examiner Signature	Date Considered
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